

Product specification Supersedes data of 1997 Feb 19 IC24 Data Handbook 1998 May 20



74LV244

FEATURES

- Wide operating voltage: 1.0 to 5.5 V
- Optimized for low voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Typical V_{OLP} (output ground bounce) < 0.8 V at V_{CC} = 3.3 V, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at V_{CC} = 3.3 V, T_{amb} = 25°C
- Output capability: bus driver
- I_{CC} category: MSI

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

DESCRIPTION

The 74LV244 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT244.

The 74LV244 is an octal non-inverting buffer/line driver with 3-State outputs. The 3-State outputs are controlled by the output enable inputs $1\overline{OE}$ and $2\overline{OE}$. A HIGH on $n\overline{OE}$ causes the outputs to assume a high impedance OFF-state. The 74LV244 is identical to the 74LV240 but has non-inverting outputs.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay 1A _n to 1Y _n ; 2A _n to 2Y _n	C _L = 15 pF; V _{CC} = 3.3 V	8.0	ns
Cl	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per buffer	$V_{CC} = 3.3 V$ V _I = GND to V _{CC} ¹	35	pF

NOTE:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W)

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz; C_L = output load capacitance in pF;

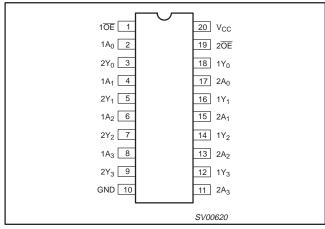
 $f_o =$ output frequency in MHz; $V_{CC} =$ supply voltage in V;

 \sum (C_L × V_{CC}² × f_o) = sum of the outputs.

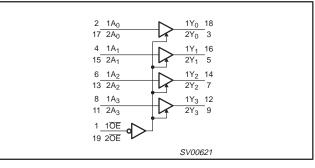
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic DIL	–40°C to +125°C	74LV244 N	74LV244 N	SOT146-1
20-Pin Plastic SO	–40°C to +125°C	74LV244 D	74LV244 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to +125°C	74LV244 DB	74LV244 DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40°C to +125°C	74LV244 PW	74LV244PW DH	SOT360-1

PIN CONFIGURATION



LOGIC SYMBOL

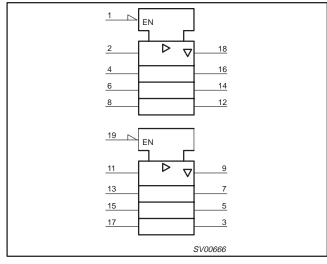


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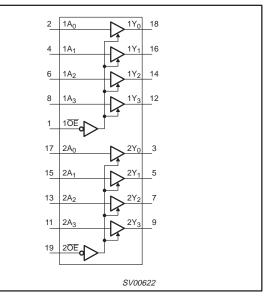
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	1 0E	Output enable input (active LOW)
2, 4, 6, 8	$1A_0$ to $1A_3$	Data inputs
3, 5, 7, 9	$2Y_0$ to $2Y_3$	Bus outputs
10	GND	Ground (0 V)
17, 15, 13, 11	$2A_0$ to $2A_3$	Data inputs
18, 16, 14, 12	$1Y_0$ to $1Y_3$	Bus outputs
19	2 <u>0E</u>	Output enable input (active LOW)
20	V _{CC}	Positive supply voltage

LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



FUNCTION TABLE

INP	OUTPUT	
nOE	nA _n	nY _n
L	L	L
L	Н	Н
Н	Х	Z

NOTES:

L = X = Z =

high impedance OFF-state

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	5.5	V
VI	Input voltage		0	-	V _{CC}	V
Vo	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$\begin{array}{l} V_{CC} = 1.0V \mbox{ to } 2.0V \\ V_{CC} = 2.0V \mbox{ to } 2.7V \\ V_{CC} = 2.7V \mbox{ to } 3.6V \\ V_{CC} = 3.6V \mbox{ to } 5.5V \end{array}$	- - - -	- - -	500 200 100 50	ns/V

NOTE:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 5.5V.

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
$\pm I_{IK}$	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5 V$	20	mA
± I _{OK}	DC output diode current	V_O < –0.5 or V_O > V_{CC} + 0.5V	50	mA
± I _O	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
± I _{GND} , ± I _{CC}	DC V _{CC} or GND current for types with – bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

				LIMITS						
SYMBOL	PARAMETER	TEST CONDITIONS	-40	°C to +8	5°C	-40°C to	o +125°C	דואט [
			MIN	TYP ¹	MAX	MIN	MAX]		
		$V_{CC} = 1.2V$	0.9			0.9				
M	HIGH level Input	$V_{CC} = 2.0V$	1.4			1.4		V		
VIH	voltage	V _{CC} = 2.7 to 3.6V	2.0			2.0		1 [×]		
		$V_{CC} = 4.5$ to 5.5V	0.7 * V _{CC}			0.7 * V _{CC}				
		$V_{CC} = 1.2V$			0.3		0.3			
V _{IL}	LOW level Input	$V_{CC} = 2.0V$			0.6		0.6			
۷IL	voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$			0.8		0.8] `		
		V _{CC} = 4.5 to 5.5			$0.3 * V_{CC}$		$0.3 * V_{CC}$			
		V_{CC} = 1.2V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A		1.2						
		V_{CC} = 2.0V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A	1.8	2.0		1.8]		
V _{OH}	HIGH level output voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μ A	2.5	2.7		2.5		V		
		V_{CC} = 3.0V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μA	2.8	3.0		2.8				
		V_{CC} = 4.5V; V_I = V_{IH} or $V_{IL;}$ – I_O = 100 μA	4.3	4.5		4.3				
V	HIGH level output voltage; BUS driver	V_{CC} = 3.0V; V_{I} = V_{IH} or $V_{IL;}$ –I_O = 8mA	2.40	2.82		2.20		v		
V _{OH}	outputs	V_{CC} = 4.5V; V_I = V_{IH} or $V_{IL;}$ – I_O = 16mA	3.60	4.20		3.50		ľ		
		V_{CC} = 1.2V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		0						
		V_{CC} = 2.0V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		0	0.2		0.2	1		
V _{OL}	LOW level output voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		0	0.2		0.2	V		
	·····g·, · · · · · ·	V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = 100 μ A		0	0.2		0.2]		
		V_{CC} = 4.5V; V_I = V_{IH} or $V_{IL;} I_O$ = 100 μ A		0	0.2		0.2			
M	LOW level output voltage; BUS driver	V_{CC} = 3.0V; V_{I} = V_{IH} or $V_{IL;}$ I_{O} = 8mA		0.25	0.40		0.50			
V _{OL}	outputs	V_{CC} = 4.5V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 16mA		0.35	0.55		0.65			
II.	Input leakage current	V_{CC} = 5.5V; V_{I} = V_{CC} or GND			1.0		1.0	μA		
I _{OZ}	3-State output OFF-state current	$V_{CC} = 3.6V; V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND}$			5		10	μΑ		
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 5.5V; V_I = V_{CC} \text{ or GND}; I_O = 0$			20.0		160	μΑ		
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_{I} = V_{CC} - 0.6V$			500		850	μΑ		

NOTE:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$.

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AC CHARACTERISTICS

GND = 0V; $t_r = t_f \le 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 1 \text{K}\Omega$

			CONDITION			LIMITS			
SYMBOL	PARAMETER	WAVEFORM	CONDITION	_	40 to +85 °	°C	-40 to -	+125 °C	UNIT
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX	
			1.2		50				
	Propagation delay		2.0		17	24		31	
t _{PHL} /t _{PLH}	$1A_n$ to $1Y_n$;	Figures 1, 2	2.7		13	17		23	ns
	2A _n to 2Y _n		3.0 to 3.6		9 ²	14		18	
			4.5 to 5.5			12		15	
		Figures 2, 3	1.2		65				
	3-State output enable time		2.0		22	39		49	
t _{PZH} /t _{PZL}	$1\overline{OE}$ to $1Y_n$;		2.7		16	29		36	ns
	$2\overline{OE}$ to $2Y_n$		3.0 to 3.6		12 ²	23		29	
			4.5 to 5.5			19		24	
			1.2		60				
	3-State output disable time		2.0		22	34		43	ns
t _{PHZ} /t _{PLZ}	$1\overline{OE}$ to $1Y_n$;	Figures 2, 3	2.7		17	24		32	
	2OE to 2Y _n	[3.0 to 3.6		13 ²	21		26	
			4.5 to 5.5			16		19	

NOTES:

1. Unless otherwise stated, all typical values are measured at $T_{amb} = 25^{\circ}C$.

2. Typical values are measured at V_{CC} = 3.3 V.

AC WAVEFORMS

 V_M = 1.5 V at $V_{CC} \geq$ 2.7 V and \leq 3.6 V V_{M} = 0.5 $\,\times\,V_{CC}$ at V_{CC} < 2.7 V and \geq 4.5 V V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load. V_X = V_{OL} + 0.3 V at $V_{CC} \geq$ 2.7 V and \leq 3.6 V V_X = V_{OL} + 0.1 $\,\times\,V_{CC}$ at V_{CC} < 2.7 V and \geq 4.5 V V_{Y} = V_{OH} – 0.3 V at V_{CC} \geq 2.7V and \leq 3.6 V V_{Y} = V_{OH} – 0.1 \times V_{CC} at V_{CC} < 2.7 V and \geq 4.5 V VI 1A_n, 2A_n INPUTS Vм GND - t_{PLH} t_{PHL} -> VOH 1Y_n, 2Y_n OUTPUT ٧м VOL SV00617

Figure 1. Input (1A_n, 2A_n) to output (1Y_n, 2Y_n) propagation delays.

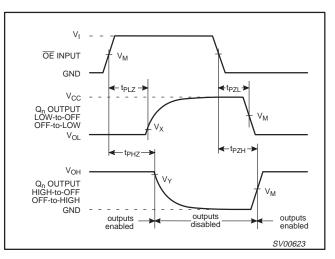


Figure 2. 3-State enable and disable times.

Product specification

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TEST CIRCUIT

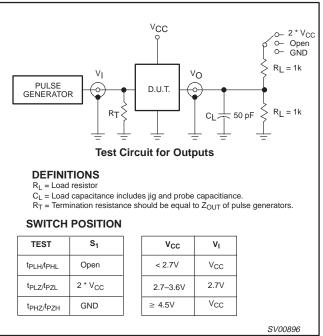


Figure 3. Load circuitry for switching times.

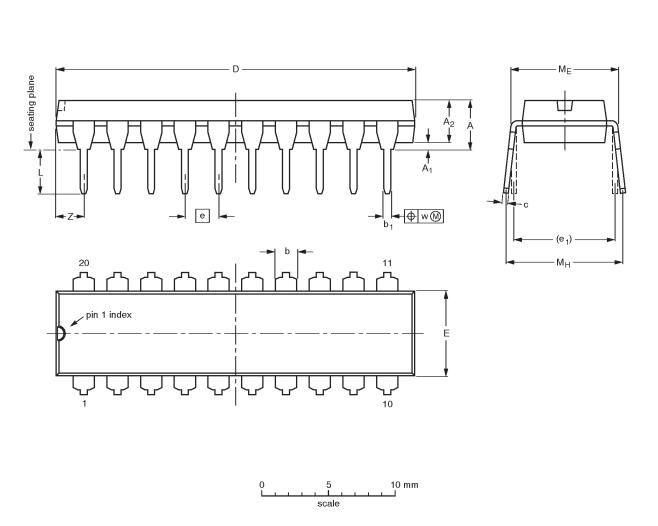
Product specification

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Octal buffer/line driver (3-State)

SOT146-1





DIMENSIONS (inch dimensions are derived from the original mm dimensions)

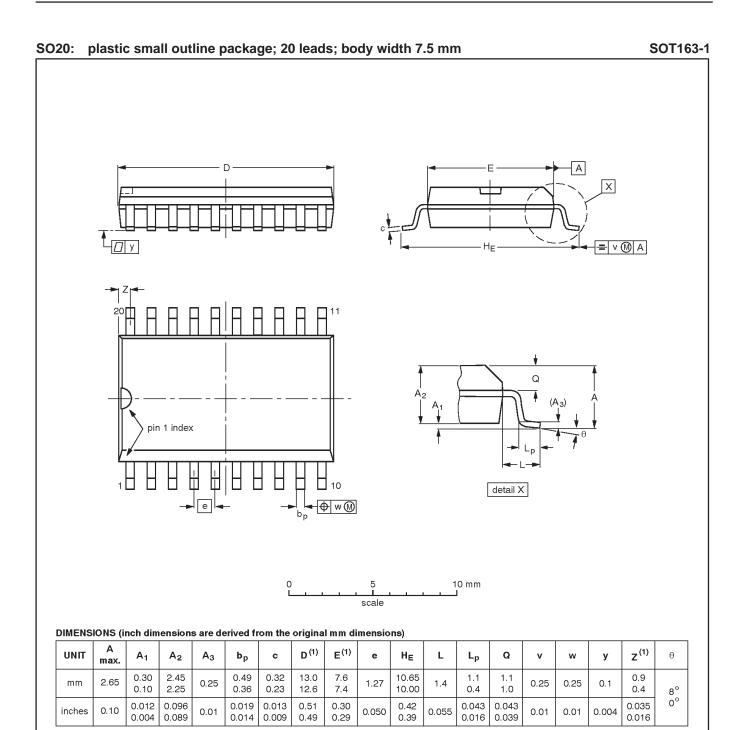
UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFEF	EUROPEAN	ISSUE DATE			
VERSION	IEC JEDEC		EIAJ		PROJECTION	ISSUE DATE	
SOT146-1			SC603			-92-11-17- 95-05-24	

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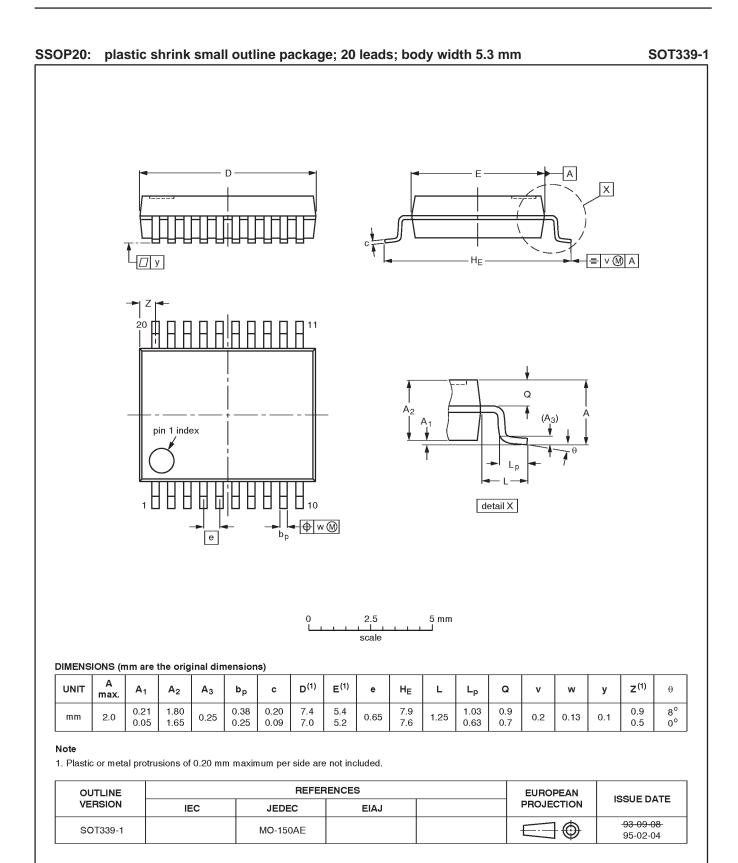


Note

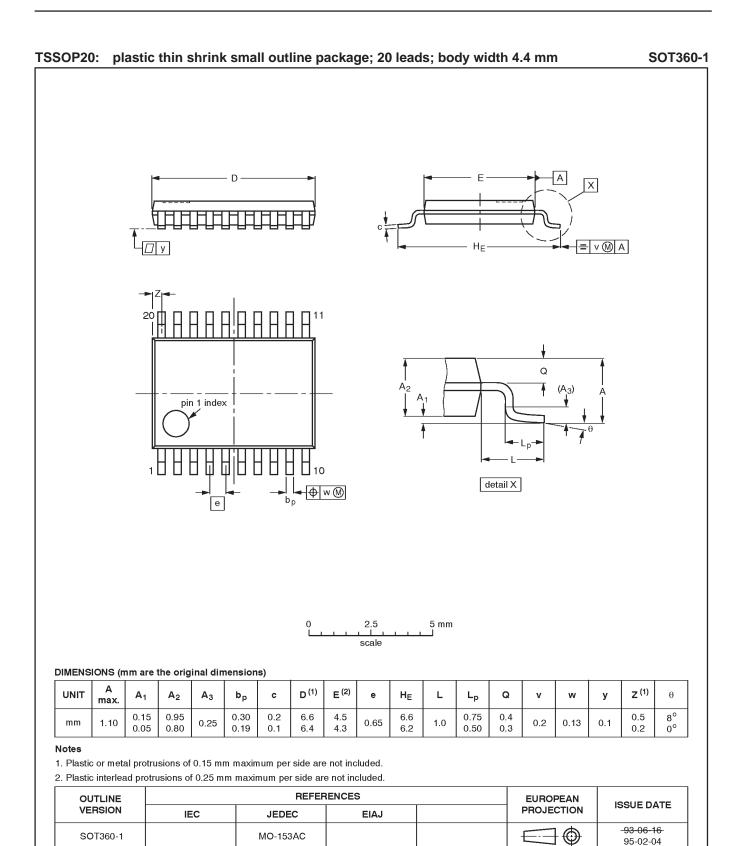
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE	REFERENCES EUROPEAN						
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013AC				-92-11-17 95-01-24	

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	DEFINITIONS						
Data Sheet Identification Product Status		Definition					
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.					
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